## **Electronic Supplementary Information**

## Thermally Driven In Situ Exsolution of Ni Nanoparticles from (Ni, Gd)CeO<sub>2</sub> for High Performance Solid Oxide Fuel Cells

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Fig. S1 Calculated lattice parameter of GNDCx as a function of Ni doping ratio (x mol%).



**Fig. S2** (a) Relative peak area of the deconvoluted non-degenerate mode with respect to  $F_{2g}$  peak area obtained from GNDC5 as a function of annealing temperature.  $R_{ext}$  (=  $A_{ext}/A_{F2g}$ ) and  $R_{int}$  (=  $A_{int}/A_{F2g}$ ) correspond to the relative amount of extrinsic and intrinsic oxygen vacancies, respectively. (b) Raman spectra of GDC15 powder calcinated at 600 °C and annealed at 800 °C and 1250 °C. Only the intrinsic vacancy peak attenuated after annealing while the extrinsic vacancy peak remains almost unchanged (inset).



**Fig. S3** Scattering intensities of lattice fringe obtained from HR-TEM images (Figure 3). Lattice spacing of (a) GNDC (200) planes from GNDC5-800 and (b) GDC (200) planes from GNDC5-1250. All lattice spacings are obtained by averaging ten intervals of the intensity peaks.



Fig. S4 Cross-sectional SEM image of GNDC5 symmetrical cell after EIS measurement confirming the electrode thickness (~20  $\mu$ m).

#	Electrode	Fabrication process	R <sub>p</sub> @ temperature	Cell type	Electrode thickness
This study	GNDC	GNDC powder screen printing	1.04 Ω cm² @ 650 °C	symmetric	~20 μm
This study	Ni-GDC	NiO-GDC powder screen printing	1.38 Ω cm² @ 650 °C	symmetric	~20 μm
[S1]	Ni-GDC	GDC powder spray coating / Ni impregnation	1.13 Ω cm² @ 850 °C	symmetric	10-20 μm
[S2]	Ni/Ag-GDC	GDC powder screen printing / Ag electroless deposition / Ni electrodeposition	1.59 Ω cm² @ 650 °C	symmetric	~8 µm
[S3]	Ni-GDC	NiO powder slurry painting / Gd, Ce impregnation	1.5 Ω cm² @ 700 °C	3-electrode	20-38 µm
[S4]	Ni-GDC	NiO-GDC powder screen printing	1.22 Ω cm² @ 650 °C	3-electrode	20-40 µm
[S5]*	Ni-SDC	NiO-GDC powder spin coating	~1 Ω cm² @ 650 °C	3-electrode	~10 µm
[S6]	Pd/Ni-GDC	NiO-GDC powder slurry painting / Pd impregnation	1.66 Ω cm² @ 650 °C	3-electrode	~30 μm

**Table S1**. Comparison of  $R_p$  of different powder-processed Ni-ceria electrodes.

\* R<sub>p</sub> at 650 °C was estimated from the given Arrhenius plot

[1] Journal of The Electrochemical Society, **2002**, 149, A1466-A1472

[2] International Journal of Hydrogen Energy, 2016, 41, 9627-9637

[3] Electrochemical and Solid-State Letters, 2004, 7, A282-A285

[4] Ceramics International, **2014**, 40, 13105–13113

[5] Journal of Membrane Science, **2009**, 334, 138–147

[6] Journal of The Electrochemical Society, 2009, 156, B1022-B1029

	R <sub>s</sub>	R <sub>HF</sub>	CPE <sub>HF</sub>	R <sub>LF</sub>	CPELF
	(Ω cm²)	(Ω cm²)	(F cm <sup>-2</sup> )	(Ω cm²)	(F cm <sup>-2</sup> )
GNDC5	4.97	0.6475*	0.3721	1.46*	0.4979
Ni-GDC composite	4.69	0.9014*	0.1996	1.79*	0.0424

 Table S2. Resistance and constant phase element (CPE) values obtained from deconvolution of EIS data.

\* It should be noted that one half of fitted value corresponds to polarization of one electrode.



**Fig. S5** Nyquist plot of GNDC5 electrode as a function of gas flow rate. Both  $R_s$  and  $R_p$  are almost identical regardless of gas flow rate, indicating that gas diffusion limit is negligible.



**Fig. S6** SEM image analysis of GNDC5 electrode (Figure 5c) to estimate TPB density induced by Ni nanocatalyst. Total perimeter of Ni nanocatalyst (yellow circles) measured using ImageJ software was 6.683  $\mu$ m. The calculated TPB density was ~ 2448 m/cm<sup>2</sup> or ~ 2.4 x 10<sup>7</sup> m/cm<sup>3</sup> assuming an electrode depth of 1  $\mu$ m.



**Fig. S7** Arrhenius plot for GNDC5 and mechanically mixed Ni-GDC composite electrode showing the  $E_a$  of 1.06 ± 0.001 eV and 1.23 ± 0.001 eV, respectively.



**Fig. S8** Nyquist plot showing  $R_p$  for GDC20 (*i.e.*, without Ni doping)-based symmetrical cells sintered at 1250 °C and reduced at 650 °C.  $R_p$  becomes significantly large without Ni nanocatalyst.



Fig. S9 Cross-sectional SEM images obtained by backscattering electron mode to confirm the AFL thickness of (a) Ni-GDC cell and (b) GNDC5 cell (scale bar =  $10 \mu m$ ).

	650 °C		600 °C		550 °C	
	$R_s (\Omega cm^2)$	$R_p (\Omega cm^2)$	$R_s (\Omega cm^2)$	$R_p (\Omega cm^2)$	$R_s (\Omega cm^2)$	$R_p (\Omega cm^2)$
GNDC5 cell	0.096	0.103	0.223	0.281	0.659	0.924
Ni-GDC cell	0.087	0.122	0.199	0.398	0.564	1.492

Table S3. The  $R_s$  and  $R_p$  of two full cells measured at 650, 600, and 550 °C.



**Fig. S10** Cross-sectional SEM image obtained by backscattering electron mode to confirm the thicknesses of GNDC5 AFL and GDC electrolyte in (a) cell-A and (b) cell-B (scale bar = 10  $\mu$ m). Solid loadings of 2.2 vol% and 2.5 vol% for GNDC5 AFL dip-coating slurry were used for fabricating cell-A and cell-B, respectively. (c) I-V characteristics and (d) EIS data are shown for comparison.